Information Disclosure Statement

New U.S. Patent Application for SEMICONDUCTOR MEMORY DEVICE HAVING ADVANCED REPAIR CIRCUIT Our Ref. No.: P02HC017/US/yh

Reference No.:

- (1) US Patent No. 6,087,889
- (2) US Patent No. 6,570,806
- (3) US Patent No. 5,663,658
- (4) US Patent No. 5,508,638
- (5) US Publication No. 2002/0196693 A1
- (6) JP Laid-Open No. 9-198897
- (7) JP Laid-Open No. 7-1766965
- (8) US Patent No. 5,424,672

Docket No.: 51876P559

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re	the Application of:	
S	Art Group:	
Application No.:		Examiner:
Filed:		
For:	Semiconductor Memory Device Having Advanced Repair Circuit	

INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. §1.97

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In accordance with the duty of disclosure, enclosed is a copy of Information Disclosure Statement by Applicant (form PTO/SB/08), which is being submitted concurrently with the Utility Application. It is respectfully requested that the cited references be considered and that the enclosed copy of PTO/SB/08 be initialed by the Examiner to indicate such consideration and a copy thereof returned to applicant(s).

-1- 51876P559

The submission of this Information Disclosure Statement is not to be construed as a representation that a search has been made in the subject application and is not to be construed as an admission that the information cited in this statement is material to patentability.

Please charge any fees due to Deposit Account 02-2666. A duplicate copy of the Fee Transmittal (PTO/SB/17) is enclosed for this purpose.

Respectfully submitted,

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Substitute for form 1449A/PTO			Complete if Known		
		Application Number			
	ATION DISCLOSURE	Filing Date			
STATEMENT BY APPLICANT (use as many sheets as necessary)		First Named Inventor	Sang-Hee Kang		
		Art Unit			
		Examiner Name			
Sheet	of	Attorney Docket Number	51876P559		

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No.¹	Document Number Number - Kind Code ² (if known)	Publication Date or Issue Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		US-6087889	07-11-2000	Mok	
		US-6570806	05-27-2003	Bertin et al.	
		US-5663658	09-02-1997	Cowles et al.	
		US-5508638	04-16-1996	Cowles et al.	
		US-2002/0196693	12-26-2002	Bertin et al.	
		US-5424672	06-13-1995	Cowles et al.	
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FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No.1	Foreign Patent Document	Publication Date MM-DD-YYYY		Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	Τ°
		Country Code ³ - Number ⁴ - Kind Code ⁵ (if known)				
		09-198897	07-31-1997	Samsung Electron Co Ltd		
		07-176696	07-14-1995	Toshiba Corp.		
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Examiner	Date	
Signature	Considered	

^{*}Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication.

¹Applicant's unique citation designation number (optional). ²See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴For Japanese patent documents, the indication of the year of reign of the Emperor must precede the serial number of the patent document. ⁵Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶Applicant is to place a check mark here if English language Translation is attached.